

UTC UNISONIC TECHNOLOGIES CO., LTD

2SC4672

NPN SILICON TRANSISTOR

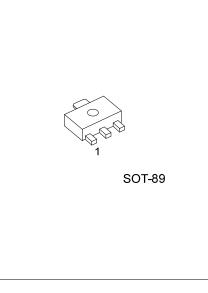
LOW FREQUENCY TRANSISTOR (50V,2A)

DESCRIPTION

The UTC 2SC4672 is a low frequency transistor. Excellent DC current gain characteristics.

FEATURES

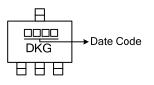
*Low Saturation Voltage, Typically V_{CE(SAT)}=0.1V at I_C / I_B=1A / 50mA *Excellent DC Current Gain Characteristics



ORDERING INFORMATION

Order Number	Packago	Pin Assignment			Docking	
	Package	1	2	3	Packing	
2SC4672G-x-AB3-R	SOT-89	В	С	Е	Tape Reel	
Note: Pin Assignment: B: Base C: Collector E: Emitter						
2SC4672G-x-AB3-R (1)Packing Type (2)Package Type (3)Rank (4)Green Package	 (1) R: Tape Reel (2) AB3: SOT-89 (3) x: refer to Classification of h_{FE} (4) G: Halogen Free and Lead Free 				e	

MARKING



■ ABSOLUATE MAXIUM RATINGS (T_A= 25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector to Base Voltage	V _{CBO}	60	V
Collector to Emitter Voltage	V _{CEO}	50	V
Emitter to Base Voltage	V _{EBO}	6	V
Collector Current	lc	2	А
Collector Current (Pulse) (Note 1)	I _{CP}	5	А
Collector Dissipation	Pc	500	mW
Junction Temperature	TJ	+150	°C
Storage Temperature	T _{STG}	-40 ~ +150	°C

Note: 1.Single pulse, P_W=10ms

2.Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_A= 25°C, unless otherwise specified)

BV _{CBO}	I _C =50μA				UNIT
	IC =50μA	60			V
BV _{CEO}	I _C =1mA	50			V
BV_{EBO}	I _E =50μA	6			V
I _{CBO}	V _{CB} =60V			0.1	μA
I _{EBO}	V _{EB} =5V			0.1	μA
V _{CE(SAT)}	I _C /I _B =1A/50mA (Note)		0.1	0.35	V
h _{FE}	V _{CE} =2V, I _C =0.5A (Note)	120		400	
f⊤	V _{CE} =2V, I _E =-0.5A, f=100MHz		210		MHz
COB	$V_{CB}=10V$, $I_E=0A$, f=1MHz		25		рF
	BV _{EBO} I _{CBO} I _{EBO} V _{CE(SAT)} h _{FE} f _T	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

Note : Measured using pulse current.

CLASSIFICATION OF h_{FE}

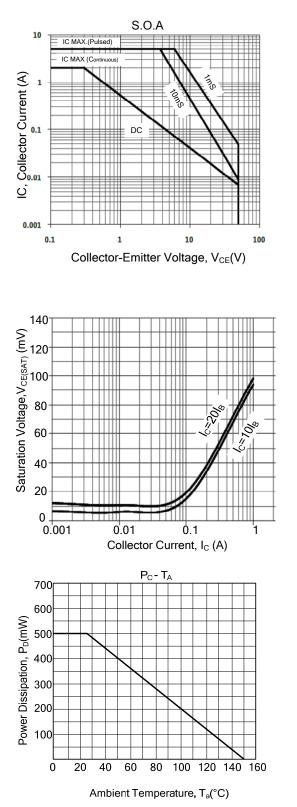
RANK	A	В
RANGE	120 ~ 240	200 ~ 400

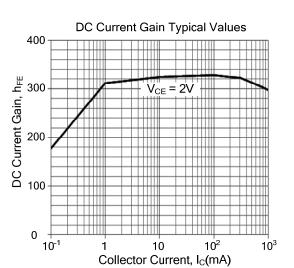


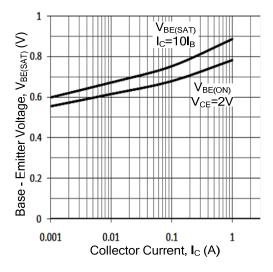
2SC4672

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TYPICAL CHARACTERISTICS









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